

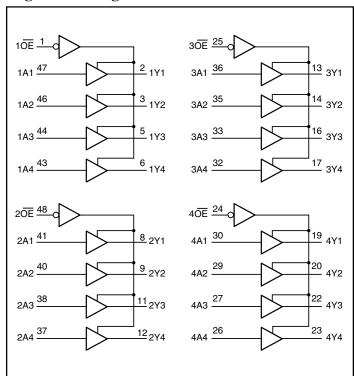
PI74LVTCH16244

3.3V 16-Bit Buffer/Line Driver with 3-State Outputs

Product Features

- Advanced low power CMOS design for 2.7V to 3.6V Vcc operation
- Supports 5V input/output tolerance in mixed signal mode operation
- · Function compatible with LVT family of products
- · Balanced ±24mA output drive
- · Typical V_{OGB} (Output Ground Bounce) < 0.8V at V_{CC} =3.3V, T_A =25°C
- · I_{off} and Power Up/Down 3-State support live insertion
- · Bus Hold on data inputs eliminates the need for external pull-up/down resistors
- · Latch-up performance exceeds 200mA Per JESD78
- · ESD protection exceeds JESD 22
 - -2000V Human-Body Model (A114-B)
 - -200V Machine Model (A115-A)
- · Industrial Temperature: -40°C to +85°C
- · Available Packages (Pb-free & Green available):
 - -48-pin 240-mil wide plastic TSSOP (A)

Logic Block Diagram



Product Description

The PI74LVTCH16244 is a non-inverting 16-bit buffer and line driver designed for low-voltage 2.7V to 3.6V V_{CC} operation, with the capability of interfacing to the 5V system environment. This buffer/driver is designed specifically to improve both the performance and density of 3-State memory address drivers, clock drivers, and busoriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

The PI74LVTCH16244 has "Bus Hold" which retains the data input's last valid logic state whenever the data input goes to high-impedance, preventing "floating" inputs and eliminating the need for pull-up/down resistors.

When Vcc is between 0 to 1.5V during power up or power down, the device is in the high-impedance state. To ensure the high-impedance state above 1.5V, \overline{OE} should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current sinking capability of the driver.

The device fully supports live-insertion with its $I_{\rm off}$ and power-up/down 3-state. The $I_{\rm off}$ circuitry disables the outputs when the power is off, preventing the backflow of damaging current through the device. Power-up/down 3-state places the outputs in the high-impedance state during power up or power down, preventing driver conflict.

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Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply voltage range, V _{CC} 0.5V to+6.5V
Input voltage range, $V_I^{(1)}$ $-0.5V$ to $+6.5V$
Voltage range applied to any output in the
high-impedance or power-off state, $V_0^{(1)}$ $-0.5V$ to $+6.5V$
Voltage range applied to any output in the
active state, $V_0^{(1,2)}$ $-0.5V$ to V_{CC} +0.5V
Input clamp current, $I_{IK}(V_I < 0)$
Output clamp current, I _{OK} (V _O <0) –50mA
Continous Output Current I _O ±50mA
Continous Current through each VCC or GND pin ±100mA
Package thermal impedance, $\theta_{JA}^{(3)}$
Storage Temperature range, T _{stg} 65°C to 150°C
Ü

Notes:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

- 1. Input negative-voltage and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- 2. This value is limited to 6.5V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

Truth Table⁽¹⁾

Inp	Outputs	
xOE	xAx	xYx
L	Н	Н
L	L	L
Н	X	Z

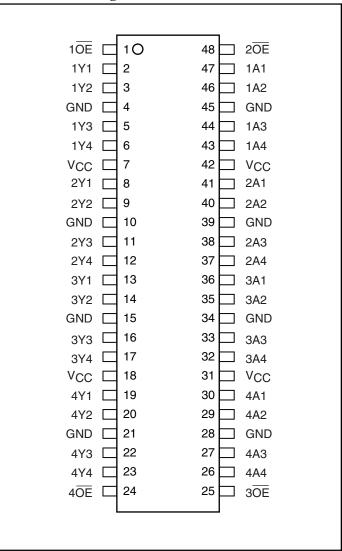
Notes:

- 1. H = High Signal Level
 - L = Low Signal Level
 - X = Don't Care or Irrelevant
 - Z = High Impedance

Product Pin Description

Pin Name	Description			
xOE	3-State Output Enable Inputs (Active LOW)			
xAx	Inputs			
xYx	3-State Outputs			
GND	Ground			
V _{CC}	Power			

Product Pin Configuration





$\textbf{Recommended Operating Conditions}^{(1)}$

		Min.	Max.	Units
V _{CC} Supply Voltage	Operating	2.7	3.6	V
V _{IH} High-level Input Voltage	$V_{CC} = 2.7V \text{ to } 3.6V$	2.0		
V _{IL} Low-level Input Voltage	$V_{CC} = 2.7V \text{ to } 3.6V$		0.8	
V _I Input Voltage	·	0	5.5	
V _O Output Voltage	High or Low State	0	V_{CC}	
	3-State	0	5.5	
I _{OH} High-level output current	$V_{CC} = 2.7V$		-12	
	$V_{CC} = 3.0 V \text{ to } 3.6 V$		-24	mA
I _O L Low-level output current	$V_{CC} = 2.7V$		12	
	$V_{CC} = 3.0 \text{V} \text{ to } 3.6 \text{V}$		24	
$\Delta t/\Delta v$ Input transition rise or fall rate			10	ns/V
$\Delta t/\Delta V_{\rm CC}$ Power-up ramp rate		150		μs/V
T _A Operating free-air temperature		-40	85	°C

^{1.} All unused inputs must be held at V_{CC} or GND to ensure proper device operation.



DC Electrical Characteristics (Over the Operating Range, T_A=-40°C+85°C)

Parameters Description			S Description Test Conditions			Min.	Max.	Units	
V _{IK} Clamp Diode Voltage		$V_{CC} = 2.7V$	$I_{\rm I} = -18 \text{mA}$			-1.2V			
		$V_{CC} = 2.7V \text{ to } 3.6V$	$I_{OH} = -100 \mu A$		V _{CC} -0.2V				
				$I_{OH} = -12mA$		2.2			
V_{OH}	Output High Voltage		V - 2V	$I_{OH} = -12mA$		2.4			
			$V_{CC} = 3V$	$I_{OH} = -24$ mA		2.2		V	
			$V_{CC} = 2.7V \text{ to } 3.6V$	I _{OL} = 100μA			0.2		
V_{OL}	Output Low Voltage		$V_{CC} = 2.7V$	$I_{OL} = 12mA$			0.4		
VOL	Output Low Voltage		V - 2V	$I_{OL} = 12mA$			0.4		
			$V_{CC} = 3V$	I_{OL} = 24mA			0.55		
	Input Leakage Current	Control Inputs	$V_{CC} = 0V \text{ to } 3.6V$	$V_{\rm I} = 0 \text{V to } 5.5 \text{V}$			±5		
т		Data Inputs	$V_{CC} = 3.6V$	$V_{\rm I} = 5.5 \rm V$		±			
I_{I}				$V_{\rm I} = V_{\rm CC}$			±5		
				$V_{\rm I} = {\rm GND}$					
		V - 2V	$V_{\rm I} = 0.8 V$		75				
$I_{I(HOLD)} \\$	Data Input Hold Current		$V_{CC} = 3V$	$V_{\rm I} = 2V$		-75			
			$V_{CC} = 3.6V^{(1)}$	$V_{\rm I} = 0 \text{ to } 3.6 \text{V}$			±500		
I_{OFF}	Power Off Output Leaks	age Current	$V_{CC} = 0V$	$V_{\rm I}$ or $V_{\rm O} = 0$ V to 5.5V			±5	μA	
I_{OZ}	3-State Output Leakage	Current	$V_{CC} = 2.7V \text{ to } 3.6V$	$V_O = 0V$ to 5.5V			±5	μι	
I _{OZPU}	Power-Up 3-State Current Power-Down 3-State Current		$V_{CC} = 0V \text{ to } 1.5V$	$V_O = 0.5V$ to 5.5V, $\overline{OE} = \text{don't care}$			±5		
I _{OZPD}			$V_{CC} = 1.5 V \text{ to } 0 V$	$V_O = 0.5V$ to 5.5V, $\overline{OE} = \text{don't care}$			±5		
I	Oniosocat Pomer Carrello Carret	Ovigogant Daviar Symply Compart V = 2.7V to 2.00	V 2 7V to 2 6V	$V_{\rm I} = V_{\rm CC}$ or GND	1 - 0		100	1	
I_{CC}	I _{CC} Quiescent Power Supply Current		$V_{CC} = 2.7V \text{ to } 3.6V$	$3.6V \le V_I \le 5.5V$	$I_{O} = 0$		100		
ΔI_{CC}	Increase in I _{CC}		$V_{CC} = 3V \text{ to } 3.6V$	One input at V_{CC} - $0.6V^{(2)}$ Other inputs at V_{CC} or GN			200		

^{1.} This is the maximum bus-hold dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

^{2.} This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



Capacitance

Parameters	Description	Test Conditions	Typ. ⁽¹⁾	Units
C_{I}	Input Capacitance	$V_{CC} = 3.3V$, $V_I = V_{CC}$ or GND	3.7	
Co	Output Capacitance	$V_{CC} = 3.3V$, $V_O = V_{CC}$ or GND	7	pF
C _{PD}	Power Dissipation Capacitance (2)	$V_{CC} = 3.3V$, $V_{I} = 0V$ or V_{CC} , $f=10$ MHz	16	1

Notes:

- 1. All typical values are measured at $V_{CC} = 3.3V$, $T_A = 25$ °C
- 2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle, C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD}= (C_{PD})(V_{CC})(f_{IN})+(I_{CC}static)

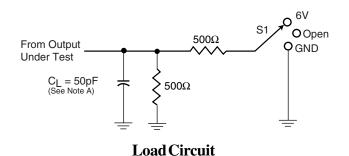
Switching Characteristics Over Operating Range

				$V_{CC} = 3.3V \pm 0.3V$			V _{CC} = 2.7V													
Parameters	Parameters Description		To (Output)	C 50 F D 500 I			C _L = 50pF, R _L = 500-ohm		Units											
				Min.	Тур.(1)	Max.	Min.	Max.												
tPLH	Delay	A	Y	1.0	2.5	3.4		3.8												
tPHL		L Delay	A	A	1.0	2.5	3.4		3.8											
t _{PZH}	Output Enable	able	Output Enable Time OE	Y	1.0	2.9	4.2		5.0											
t _{PZL}	Time			OL	J.L	OL	OL	J.L	J.L	OL	OL	OL	OL	OL	OL	1	1.0	3.0	4.2	
t _{PHZ}	Time OE	Y	1.0	2.5	4.0		4.7													
$t_{\mathrm{PL}Z}$		Y	1.0	2.4	3.9		4.3													
t _{SK(O)}	Output to Output Skew ⁽²⁾					0.5														

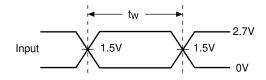
- 1. All typical values are measured at $V_{CC} = 3.3V$, $T_A = 25$ °C
- 2. Skew between any two outputs, switching in the same direction.



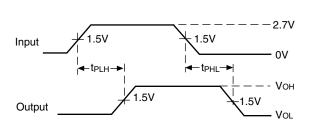
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.7V$ and $3.3V \pm 0.3V$



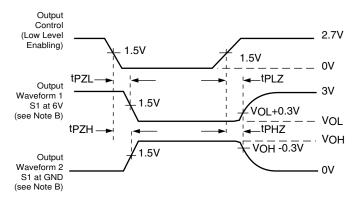
Test	S1
tplH/tpHL	Open
tpLZ/tpZL	6V
tpHZ/tpZH	GND



Voltage Waveforms Pulse Duration



Voltage Waveforms Propagation Delay Times



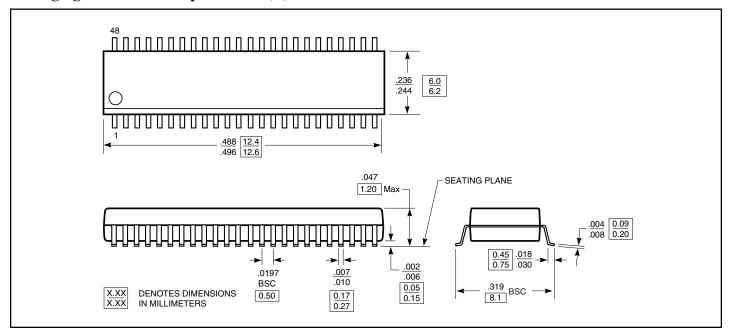
Voltage Waveforms Enable and Disable Times

Figure 1. Load Circuit and Voltage Waveforms

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input impulses are supplied by generators having the following characteristics: PRR £ 10 MHz, Z_O = 50W, t_R £ 2.5ns, t_F £ 2.5ns.
- The outputs are measured one at a time with one transition per measurement.



Packaging Mechanical: 48-pin TSSOP(A)



Ordering Information

Ordering Code	Package Code	Package Description
PI74LVTCH16244A	A	48-pin, 240-mil wide plastic TSSOP
PI74LVTCH16244AE	A	Pb-free, 48-pin, 240-mil wide plastic TSSOP

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free & Green
- Adding an X suffix = Tape/Reel